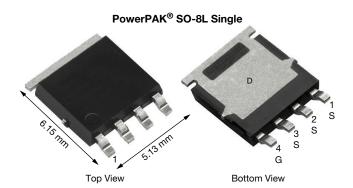


www.vishay.com

Vishay Siliconix

Automotive P-Channel 30 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY				
V _{DS} (V)	-30			
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.0092			
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.0146			
I _D (A)	-30			
Configuration	Single			

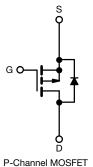
FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % Rq and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





COMPLIANT HALOGEN FREE



ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and halogen-free	SQJA37EP (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unles	s otherwise noted	1)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage Gate-source voltage		V _{DS}	-30	V	
		V_{GS}	± 20	V	
Continuous drain current a	T _C = 25 °C	1_	-30		
Continuous drain current "	T _C = 125 °C	I _D	-30		
Continuous source current (diode conduction) ^a		I _S	-30	Α	
Pulsed drain current ^b		I _{DM}	-120		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	-26		
Single pulse avalanche energy	L = 0.1 111111	E _{AS}	33.8	mJ	
Maximum nawar dissination b	T _C = 25 °C	В	45	W	
Maximum power dissipation b $T_C = 125 ^{\circ}\text{C}$	P_{D}	15	VV		
Operating junction and storage temperature range	ge	T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temperature)	d, e		260	C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount c	R_{thJA}	70	°C/W
Junction-to-case (drain)		R_{thJC}	3.3	C/VV

Notes

- a. Package limited
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- c. When mounted on 1" square PCB (FR4 material)
- d. See solder profile (www.vishav.com/doc?73257). For PowerPAK SO-8L, the end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components



Vishay Siliconix

PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static					•		
Drain-source breakdown voltage	V _{DS}	V_{GS}	= 0, I _D = -250 μA	-30	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	V _{GS} , I _D = -250 μA	-1.5	-2.0	-2.5	V
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA
		V _{GS} = 0 V	V _{DS} = -30 V	-	-	-1	
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V	V _{DS} = -30 V, T _J = 125 °C	-	-	-50	μΑ
		V _{GS} = 0 V	V _{DS} = -30 V, T _J = 175 °C	-	-	-200	
On-state drain current ^a	I _{D(on)}	V _{GS} = -10 V	V _{DS} ≥ -5 V	-20	-	-	Α
		V _{GS} = -10 V	I _D = -6 A	-	0.0076	0.0092	
	_	V _{GS} = -10 V	I _D = -6 A, T _J = 125 °C	-	-	0.0112	
Drain-source on-state resistance ^a	$R_{DS(on)}$	V _{GS} = -10 V	I _D = -6 A, T _J = 175 °C	-	-	0.0122	Ω
		V _{GS} = -4.5 V	I _D = -5 A	-	0.0120	0.0146	
Forward transconductance b	9 _{fs}	V _{DS}	= -15 V, I _D = -6 A	-	32	-	S
Dynamic ^b						l.	
Input capacitance	C _{iss}			-	3620	4900	
Output capacitance	C _{oss}	V _{GS} = 0 V	V _{DS} = -25 V, f = 1 MHz	-	360	500	рF
Reverse transfer capacitance	C _{rss}	1		-	346	470	
Total gate charge ^c	Qg			-	65	100	
Gate-source charge ^c	Q _{qs}	V _{GS} = -10 V	$V_{DS} = -15 \text{ V}, I_{D} = -5 \text{ A}$	-	9	-	nC
Gate-drain charge ^c	Q _{qd}			-	12	-	
Gate resistance	R _q		f = 1 MHz	2.4	4.8	7.2	Ω
Turn-on delay time ^c	t _{d(on)}			-	12	20	
Rise time ^c	t _r	V _{DD} :	= -15 V, R _I = 3 Ω	-	4	10	
Turn-off delay time ^c	t _{d(off)}		$V_{\rm GEN} = -10 \rm V, R_g = 1 \Omega$	-	64	100	ns
Fall time ^c	t _f			_	24	40	
Source-Drain Diode Ratings and Charac	teristics b					l.	
Pulsed current ^a	I _{SM}			-	-	-120	Α
Forward voltage	V _{SD}	I _F =	-6 A, V _{GS} = 0 V	-	-0.78	-1.2	V
Body diode reverse recovery time	t _{rr}			-	22	45	ns
Body diode reverse recovery charge	Q_{rr}	1 _ 4	A, di/dt = 100 A/µs	-	11	25	nC
Reverse recovery fall time	ta] I _F = -4	A, ui/ut = 100 A/μS	-	11	-	ns
Reverse recovery rise time	t _b			-	11	-	119
Body diode peak reverse recovery current	I _{RM(REC)}			-	-0.9	-	Α

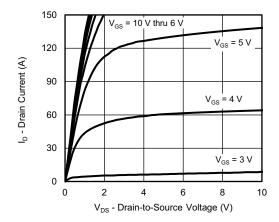
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

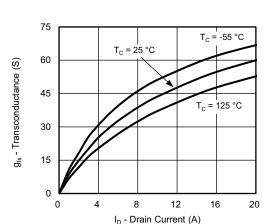
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



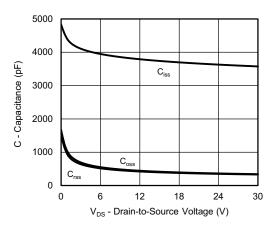
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



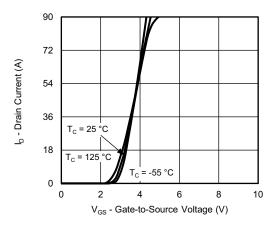
Output Characteristics



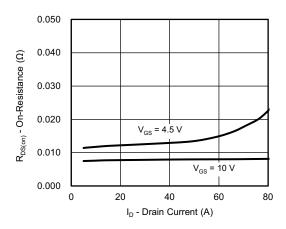
Transconductance



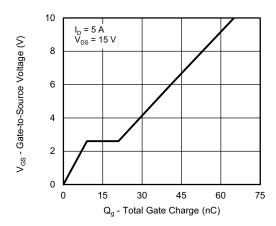
Capacitance



Transfer Characteristics



On-Resistance vs. Drain Current

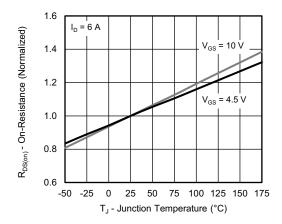


Gate Charge

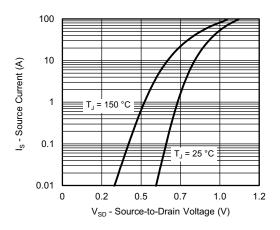
For technical questions, contact: automostechsu



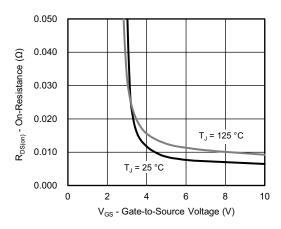
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



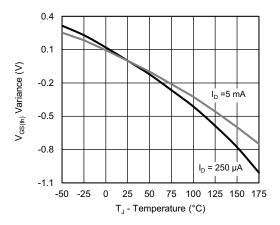
On-Resistance vs. Junction Temperature



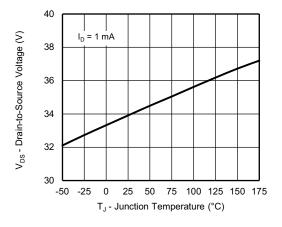
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage

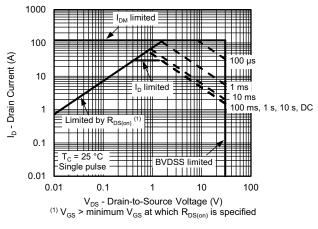


Drain-Source Breakdown vs. Junction Temperature

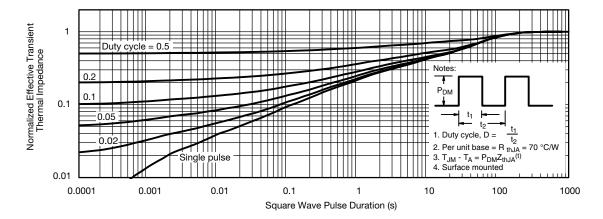
For technical questions, contact: automostech



THERMAL RATINGS (T_C = 25 °C, unless otherwise noted)



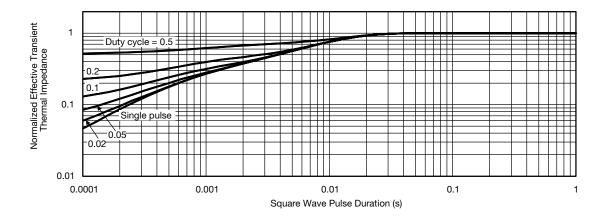
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_C = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

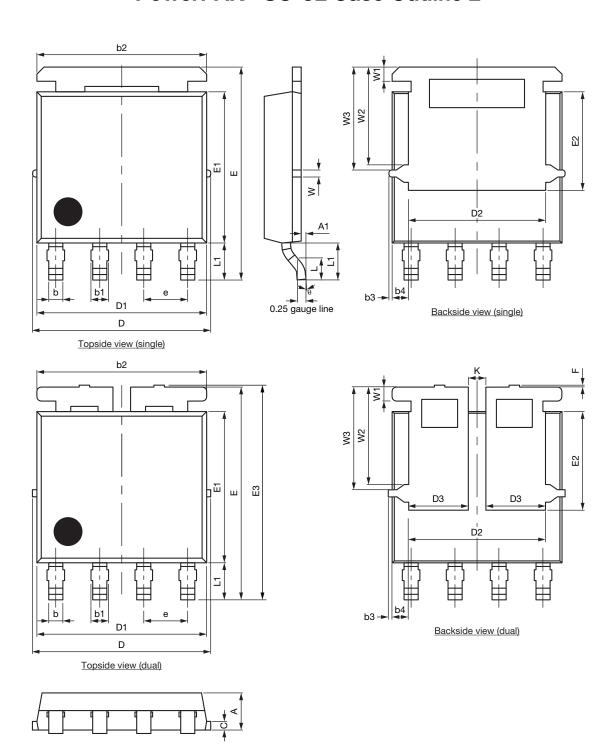
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg275171.



PowerPAK® SO-8L Case Outline 2



Vishay Siliconix

DIM		MILLIMETERS			INCHES		
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX	
Α	1.00	1.07	1.14	0.039	0.042	0.045	
A1	0.00	-	0.127	0.00	-	0.005	
b	0.33	0.41	0.48	0.013	0.016	0.019	
b1	0.44	0.51	0.58	0.017	0.020	0.023	
b2	4.80	4.90	5.00	0.189	0.193	0.197	
b3		0.094			0.004		
b4		0.47			0.019		
С	0.20	0.25	0.30	0.008	0.010	0.012	
D	5.00	5.13	5.25	0.197	0.202	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D3	1.63	1.73	1.83	0.064	0.068	0.072	
е		1.27 BSC		0.050 BSC			
Е	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	2.75	2.85	2.95	0.108	0.112	0.116	
E3	6.05	6.22	6.40	0.238	0.245	0.252	
F	-	-	0.15	-	-	0.006	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
K		0.51			0.020		
W		0.23		0.009			
W1		0.41		0.016			
W2		2.82			0.111		
W3		2.96		0.117			
θ	0°	-	10°	0°	-	10°	

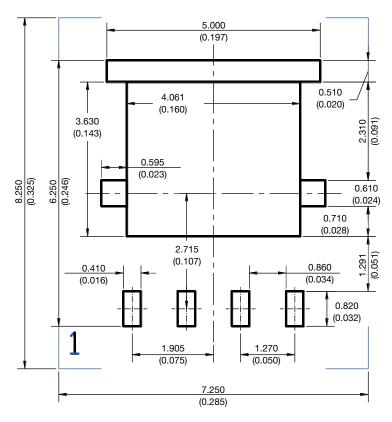
DWG: 6044

Note

• Millimeters will govern



RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L SINGLE



Recommended Minimum Pads Dimensions in mm (inches)



Legal Disclaimer Notice

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